ENGINEERING STATEMENT

For Type Certification of

Cobra Electronics Corporation

Model No: FRS 120 FCC ID: BBOFRS120C

I am an Electronics Engineer, a principal in the firm of Hyak Laboratories, Inc., Springfield, Virginia. My education and experience are a matter of record with the Federal Communications Commission.

Hyak Laboratories, Inc. has been authorized by Cobra Electronics Corporation to make type certification measurements on the FRS 120 transceiver. These tests made by me or under my supervision in our Springfield laboratory.

Test data and documentation required by the FCC for Type Certification are included in this report. The data verifies that the above mentioned transceiver meets FCC requirements and Type Certification is requested.

Rowland S. Johnson

Dated: November 28, 2000

A. INTRODUCTION

The following data are submitted in connection with this

request for type certification of the FRS 120 transceiver in accordance with Part 2, Subpart J of the FCC Rules.

The FRS 120 is a portable, battery operated, UHF, frequency modulated transceiver intended for 12.5 kHz channel family radio service applications in the 462.5625-467.7125 MHz band. It operates from a nominal 4.5 Vdc battery supply. MFR rated output power is 0.5 watts ERP.

- B. GENERAL INFORMATION REQUIRED FOR TYPE CERTIFICATION (Paragraph 2.983 of the Rules)
 - 1. Name of applicant: Cobra Electronics Corporation
 - 2. Identification of equipment: FCC ID: BBOFRS120C
 - a. The equipment identification label is submitted as a separate exhibit.
 - b. Photographs of the equipment are submitted as a separate exhibit.
 - 3. Quantity production is planned.
 - 4. Technical description:
 - a. 11k0F3E emission
 - b. Frequency range: 462.5625 467.7125 MHz.
 - c. Operating power of transmitter is fixed at the factory at less than 0.5 W ERP.
 - d. Maximum power permitted is 0.5 watts, and the FRS 120 fully complied with that power limitation.
 - e. The dc voltage and dc currents at final amplifier:

Collector voltage: 4.4 Vdc Collector current: 0.53 A

- f. Function of each active semiconductor device: See Appendix 1.
- g. Complete schematic diagram is submitted as a separate exhibit.
- h. A draft instruction manual is submitted as a separate exhibit.
- i. The transmitter tune-up procedure is submitted as a separate exhibit.

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- B. GENERAL INFORMATION (continued)
 - j. A description of circuits for stabilizing frequency is included in Appendix 2.
 - k. A description of circuits and devices employed for suppression of spurious radiation and for limiting modulation is included in Appendix 3.
 - 1. Not applicable.

- 5. Data for 2.985 through 2.997 follow this section.
- C. <u>RF Power Output</u> (Paragraph 2.985(a) of the Rules)

The FRS 120 has a permanently attached built-in antenna without provisions for a coaxial connector.

RF power output was determined by substitution.

TABLE 1

Operating Freq., MHz

Power watts into a dipole antenna

462.5625

0.481

D. MODULATION CHARACTERISTICS

- 1. A curve showing frequency response of the transmitter is shown in Figure 1. Reference level was audio signal output from a Boonton 8220 modulation meter with one kHz deviation. Audio output was measured with an Audio Precision System One integrated test system.
- 2. Modulation limiting curves are shown in Figure 2, using a Boonton 8220 modulation meter. Signal level was established with a Audio Precision System One integrated test system. The curves show compliance with paragraphs 2.987(b).
- 3. Figure 3 is a graph of the post-limiter low pass filter which provides a roll-off of 60Logf/3 dB where f is audio frequency in kHz. Measurements were made following EIA RS-152B with an Audio Precision System One integrated test system on the Boonton 8220 modulation meter audio output.

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4. <u>Occupied Bandwidth</u> (Paragraphs 2.989(c) of the Rules)

Figure 4 is a plot of the sideband envelope of the transmitter output taken with a Tektronix 494P spectrum analyzer. Modulation corresponded to conditions of 2.989(c)(1) and consisted of 2500 Hz tone at an input level 16 dB greater than that necessary to produce 50% modulation at 2669 Hz, the frequency of maximum response. Measured modulation under these conditions was $1.8~\mathrm{kHz}$.

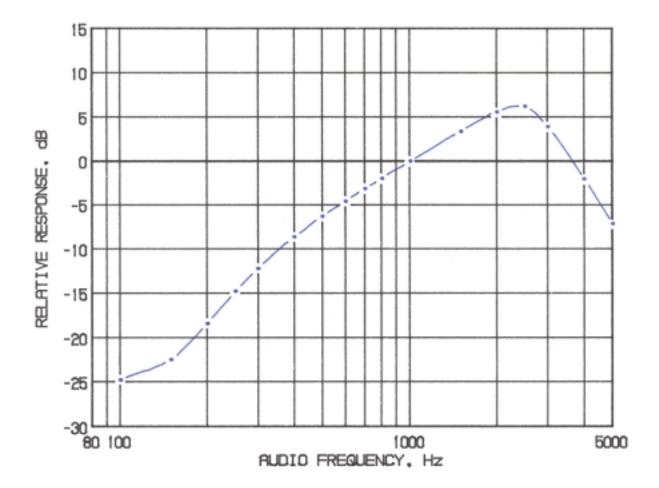
Emission designator:

 $(2M + 2D) (2 \times 3 \text{ kHz}) + (2 \times 2.5 \text{ kHz}) = 11\text{kOF3E}$

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FIGURE 1

MODULATION FREQUENCY RESPONSE



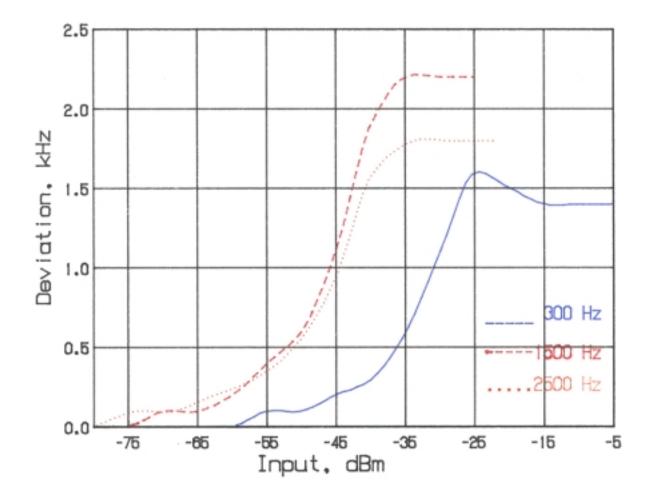
MODULATION FREQUENCY RESPONSE FCC ID: BBOFRS120C

FIGURE 1

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AUDIO LIMITER CHARACTERISTICS

FIGURE 2

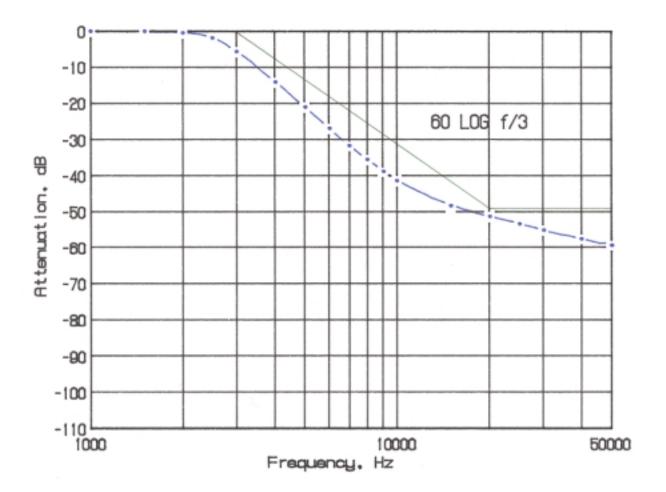


AUDIO LIMITER CHARACTERISTICS FCC ID: BBOFRS120C

FIGURE 2

FIGURE 3

AUDIO LOW PASS FILTER RESPONSE



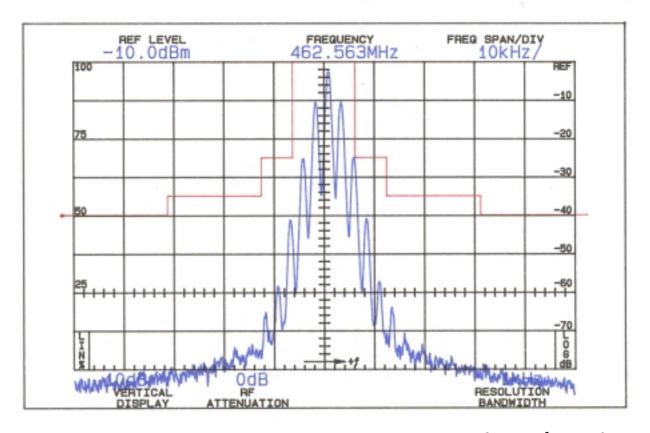
AUDIO LOW PASS FILTER RESPONSE FCC ID: BBOFRS120C

FIGURE 3

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FIGURE 4

OCCUPIED BANDWIDTH



ATTENUATION IN dB BELOW MEAN OUTPUT POWER Required

On any frequency more than 50% up to and including 100% of the authorized bandwidth, 12.5 kHz (6.25-12.5 kHz)

25

On any frequency more than 100%, up to and including 250% of the authorized bandwidth (12.5-31.25 kHz)

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On any frequency removed from the assigned frequency by more than 250% of the authorized bandwidth (over 31.25 kHz)

43+10 LogP = 40(P = 0.481)

OCCUPIED BANDWIDTH FCC ID: BBOFRS120C

FIGURE 4

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D. MODULATION CHARACTERISTICS (Continued)

The plots are within FCC limits. The horizontal scale frequency) is $10~\mathrm{kHz}$ per division and the vertical scale amplitude) is a logarithmic presentation equal to $10~\mathrm{dB}$ per division.

E. SPURIOUS EMISSIONS AT THE ANTENNA TERMINALS (Paragraph 2.991 of the Rules)

The FRS 120 has a permanently attached antenna. There is no connector for an external antenna. Therefore, no antenna terminal conducted measurements were made.

F. DESCRIPTION OF RADIATED SPURIOUS MEASUREMENT FACILITIES

A description of the Hyak Laboratories' radiation test facility is a matter of record with the FCC. The facility was accepted for radiation measurements from 25 to 1000 MHz on October 1, 1976 and is currently listed as an accepted site.

G. MEASUREMENTS OF SPURIOUS RADIATION

Measurements of radiated spurious emissions from the FRS 120 were made by substitution method with a Tektronix 494P spectrum analyzer using Singer DM-105 for the measurements to 1 GHz, and EMCO 3115 horn to $4.8~\mathrm{GHz}$.

The transmitter was located in an open field 3 meters from the test antenna. Supply voltage was a power supply with a terminal voltage under load of 4.5 Vdc.

The transmitter and test antennae were arranged to maximize pickup. Both vertical and horizontal test antenna polarization were employed.

Measurements were made from the lowest frequency generated within the unit (12.8 MHz), to 10 times operating frequency. Data after application of antenna gain factors and line loss corrections are shown in Table 2.

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TABLE 2

TRANSMITTER CABINET RADIATED SPURIOUS

462.5625 MHz, 4.5 Vdc, 0.481 watts

Spurious
Frequency
MHz

dB Below Carrier <u>Reference</u>

1387.690	54
1850.252	55

Required: $43+10 \operatorname{Log}(P) = 40$

All other spurious from 21.25 MHz to the tenth harmonic were 20 dB or more below FCC limit.

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H. FREQUENCY STABILITY (Paragraph 2.995(a)(2))

Measurement of frequency stability versus temperature was made at temperatures from -20°C to $+50^{\circ}\text{C}$. At each temperature, the unit was exposed to test chamber ambient a minimum of 60 minutes after indicated chamber temperature ambient had stabilized to within $\pm 2^{\circ}$ of the desired test temperature. Following the 1 hour soak at each temperature, the unit was turned on, keyed and frequency measured within 2 minutes. Test temperature was sequenced in the order shown in Table 3, starting with -20°C .

A Thermotron S1.2 temperature chamber was used. Temperature was monitored with a Keithley 871 digital thermometer. The

transmitter output stage was terminated in a dummy load. Primary supply was 4.5 volts. Frequency was measured with a HP 5385A frequency counter connected to the transmitter through a power attenuator. Measurements were made at 462.5625 MHz. No transient keying effects were observed.

TABLE 3

FREQUENCY STABILITY AS A FUNCTION OF TEMPERATURE 462.5625 MHz, 4.5 Vdc, 0.481 W

Temperature, °C	Output_Frequency,_MHz	p.p.m.
-19.8	462.563983	1.8
- 9.5	462.563950	1.7
- 0.3	462.563495	0.7
9.8	462.563384	0.5
20.0	462.563288	0.3
30.6	462.563041	-0.3
40.1	462.562525	-1.4
49.7	462.562283	-1.9
Maximum frequency error:	462.562283	
	462.562500	
	000886 MHz	

FCC Rule 95.627(b) specifies .00025% (2.5 p.p.m.) or a maximum of ± 0.001156 MHz, which corresponds to:

High Limit	462.563656	MHz
Low Limit	462.561344	MHz

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I. FREQUENCY STABILITY AS A FUNCTION OF SUPPLY VOLTAGE (Paragraph 2.995(d)(2) of the Rules)

Oscillator frequency as a function of power supply voltage was measured with a HP 5385A frequency counter as supply voltage provided by an HP 6264B variable dc power supply was varied from $\pm 15\%$ above the nominal 4.5 volt rating to below the battery end point. A Fluke 197 digital voltmeter was used to measure supply voltage at transmitter primary input terminals. Measurements were made at $20\,^{\circ}\text{C}$ ambient.

FREQUENCY STABILITY AS A FUNCTION OF SUPPLY VOLTAGE

462.5625 MHz, 4.5 Vdc Nominal; 0.481W

Supply_V	oltage_	Output_Frequency,_MHz	p.p.m.
5.17	115%	462.563588	0.4
4.95	110%	462.563528	0.3
4.73	105%	462.563529	0.3
4.50	100%	462.563520	0.3
4.28	95%	462.563448	0.1
4.05	90%	462.563455	0.1
3.83	85%	462.563459	0.1
3.60*	80%	462.563464	0.1
Maximum	frequency error:	462.563588	
		462.562500	
		+ .000187 MHz	

FCC Rule 95.627(b) specifies .00025% (2.5 p.p.m. or a maximum of ± 0.001156 MHz, corresponding to:

High Limit	462.563656	MHz
Low Limit	462.561344	\mathtt{MHz}

^{*}Battery end point.

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APPENDIX 1

FUNCTION OF DEVICES/PARTS LIST FRS 120

	0.00	ALL STATES
Description	Qty Reqd.	
CAP-CHIPTAN 10UF- M 6V3 C1206	2	C17,C36
CAP-CHIP 100PF J 50V C0603 CH-	2 1	C49,C76 C59
CAP-CHIP 1NF K 50V C0603 B	11	C07,C09,C11,C67,C83,C30,
CAP-CHIP 10NF- K 50V C0603 B	431 11	C47,C46,C41,C62,C45
0.00 0.00 400ME 7.40M 00000 F	10	C14,C15,C16,C68,C80,
CAP-CHIP 100NF Z 16V C0603 F	10	
	-	C82,C27,C29,C28,C66
CAP-CHIP 1UF- Z 25V C0805 F-	5	C72,C79,C81,C18,C73
CAP-CHIP 12PF- J 50V C0603 CH-	2	C56,C40
CAP-CHIP 1P5F- C 50V C0603 CH-	1	C34
CAP-CHIP 18PF- J 50V C0603 CH-	3	C52,C48,C31 C33
CAP-CHIP 2PF- C 50V C0603 CH-	1	
CAP-CHIP 22PF- J 50V C0603 CH-	2	C10,C43
CAP-CHIP 220PF J 50V C0603 CH-	1	C13 C12
CAP-CHIP 2N2F- K 50V C0603 B-	1	
CAP-CHIP 22NF- K 50V C0603 B-	4	C64,C70,C69,C63
CAP-CHIP 3PF- C 50V C0603 CH-	7	C55,C54,C01,C60,C44,C53.C35
CAP-CHIP 3N3F- K 50V C0603 B-	1	C32
CAP-CHIP 4PF C 50V C0603 CH-	3	C39,C37,C06
CAP-CHIP 470PF J 50V C0603 CH-	2	C50,C75
CAP-CHIP 7PF D 50V C0603 CH-	5	C57,C58,C38,C08,C42
CAP-CHIP 5PF C 50V C0603 CH-	4	C02,C03,C04,C05
CAP-CHIP 560PF J 50V C0603 CH-	1	C78 ·
CAP-CHIP 6N8F- J 50V C0603 B	1	C77
CAP-CHIP 820PF K 50V C0603 B-	1	C71
DIODE SW- 1SS314 SOD323 35V-	3	D04,D01,D06
DIODE SW- 1SS355 SOD323 80V-	1	D02
DIODE VAR 1SV214 SOD323 30V-	1	D03
CHIP INDUCTOR 12NH- +-5%- 0603	7	L01,L10,L11,L02,L03,L04,L06
CHIP INDUCTOR 18NH- +-5%- 0603	3	L13,L15,L05
INDUCTOR 2U2H- +-10% 0805 LQG	2 1	L07
CHIP INDUCTOR 27NH- +-5%- 0603	2	L14,L12
THERMISTER 0220JBA A 22- SMD-	1	TR01
RES-CHIP 10R- OHM J 1/16W 0603	1	R25
RES-CHIP 1K - OHM J 1/16W 0603	1	R36
RES-CHIP 10K- OHM J 1/16W 0603	4	R17,R34,R05,R41
RES-CHIP 100K OHM J 1/16W 0603	2	R48,R30
RES-CHIP 1M OHM J 1/16W 0603	3	R13,R59,R40
RES-CHIP 15K- OHM J 1/16W 0603	1	R31
RES-CHIP 22R- OHM J 1/16W 0603	1	R20
RES-CHIP 220R OHM J 1/16W 0603	3	R28,R63,R47
RES-CHIP 2K2- OHM J 1/16W 0603	2	R15,R18
RES-CHIP 22K- OHM J 1/16W 0603	6	R19,R39,R38,R46,R43,R08
RES-CHIP 270K OHM J 1/16W 0603	2	R10,R42
RES-CHIP 330R OHM J 1/16W 0603	2	R03,R54
RES-CHIP 33K- OHM J 1/16W 0603	2	R14,R49
RES-CHIP 3K9- OHM J 1/16W 0603	8	R23,R24,R16,R26,R21,
KEG-CI III SKG-CI IIII G II IGTT GGGG	,•.	R58,R37,R27
RES-CHIP 47R- OHM J 1/16W 0603	1	R35
RES-CHIP 4K7- OHM J 1/16W 0603	1	R11
RES-CHIP 47K- OHM J 1/16W 0603	9	R29,R45,R52,
RES-CHIP 47 R- OHM 5 1/1044 0000	•	R53,R51,R50,R01,R09,R44
RES-CHIP 470K OHM J 1/16W 0603	1	R06
	i	R56
RES-CHIP 5K6- OHM J 1/16W 0603	2	R22.R02
RES-CHIP 100R OHM J 1/16W 0603	1	R32
RES-CHIP 68K- OHM J 1/16W 0603	1	R04
RES-CHIP 680R OHM J 1/16W 0603		
RES-CHIP 820K OHM J 1/16W 0603	1	R07
RES-CHIP 8K2- OHM J 1/16W 0603	1	R57
TRS SSB DTA143EKA SC59 PNP	2	Q05,Q09

★ 10 00 10 00 00	0300000000	0.6		
Description	Qty Reqd.			100
TRS SSB DTA143TKA SC59 PNP	1	Q04		
TRW SSB HN3C10FT NPN	4	Q06		
TRS SSB 2SC2712GR— SOT23- NPN	. 1	Q10		
TRS SSB 2SC4226R24 SOT23 NPN	2	Q01,Q07		
FET NC- 2SK3078 SC62	1	Q08		
FET NC- 3SK320	1	Q02		
IC DBL5018V SOP16	1	IC01		
IC LM324N DIP14 OPAMP	1	IC04		
IC M64028AGP SSOP16 PLL	1	IC02		
IC S80820ANUP-EDHT2 SOT89- REEL 2		IC07		
IC LM386M-1 SOIC8 AUDIO PO		IC03		
TRS SSB DTC114EKA SC59 NPN	2	Q03,Q11		
IC HT48C30 SOP28 CPU	1	IC05		
IC XC62FP3002PR SOT89- REEL 3V V	(1	IC06		
CAP-ELE 100UF- M 10V MINI	1	C84		
VAP-CAP 6P5 30PF TZC03P300A110	1	TC01		
CRY FILTER 21M4HZ HC45/U	1	FLT02		
CERFILTER 450KHZ LT450HT L8W6	3 1	FLT03		
IFT 700UH 8% L7.5W7.5H8	1	L08		
IFT 105NH 8% L5.4W5.4H865	1	L09		
VR TRIMMER 5K N EVND8Y	. 2	VR02,VR03		
MICROPHONE -62DB 2V5- EM-926A- 62		MIC01		
CER RESONATOR 4MHZ L8W3H5.5	1	X02 '		
CRYSTAL 20M95HZ- 5PPM HC45/U 15I		X01		
JACK MONO F DHOR ST-002	i	J02		
JACK MONO F DHOR ST-613	1	J01		
VR TRIMMER 5K- N RV091NS	1	VR01		
	1	SP01		
SPEAKER- D36MM 80HM 0.5W-	1	- 53 ft. 577 km		
CAP-ELE 220UF- M 10V- MINI	1,7	C51,C26,C65		
CAP-CHIP 100NF Z 16V C0603 F-	1	C401		
LED GREEN KPA-3010GR-	2	D401,D402		
IC HT1621 DICE LCD CONTF		IC401		
FLAT 340 12 P1.00	1	J201		
HEATSEAL 010T L012 P1.80	. 1	J202		
LCD TNG TTR5302DPFDH TNSF PLZR L	.i 1	LCD01		
120 PANEL LENS, with printing	្ប			
BATTERY DOOR	1.			
VOLUME RNOB	-1			
ANTENNA CAP	1			
BATTERY DOOR LOCK				
FRONT CASE	■ Pr#127			
REAR CASE	1			
BELT CLIP	1			
BEZEL, SNAP ON COVER	1			
RF SHIELD CAN	1			
LOCK PIN	1			
ST SCREW 2.6 x 8, BB Head, Ni plated	2			
ST SCREW 3.0 x 8, BB Head, Ni plated	2			
SPEAKER NET DIA.35	1			
DOUBLE SIDE TAPE LIGHIGUIDE	1		E	
3 Keys keypad, black color	1			
PTT / Talk BUTTON	1			
JACK COVER	1			
Hand strip	1			
Dome, Dia = 6, Type no = 6BT- L	2			
BEZEL, SNAP ON COVER	0.5			
BEZEL, SNAP ON COVER	0.5			
DELLE, GIANI ON GOVER	0.0			

APPENDIX 2

CIRCUITS AND DEVICES TO STABILIZE FREQUENCY

SYNTHESIZER

A phase locked loop (PLL) circuit establishes and stabilizes operating frequency.

The data for producing necessary frequencies is established by the CPU on the digital board.

The frequency stability of the TX/RX is maintained by the TCXO, which generates a stable frequency of 12.8 MHz.

CIRCUITS AND DEVICES TO STABILIZE FREQUENCY FCC ID: BBOFRS120C

APPENDIX 3

CIRCUITS TO SUPPRESS SPURIOUS RADIATION AND LIMIT MODULATION

Circuitry to Suppress Spurious Emissions

The transmitted signal of approximately 16 dBm, combined at the PLL circuit is supplied to the base of the Q701 amplifier. The transmitted signal amplified to 27 dBm here passes the TX LPF of the $2^{\rm nd}$ characteristic of the C703, L702, L701, L700 and TX/TX switching takes place by the D701. After this, the signal is provided to the antenna.

Circuitry to Limit Modulation and Audio Low Pass Filter

The voice signal input from the microphone is pre-emphasized at the IC104B, and at the same time, the components below 300 Hz are reduced to minimize the influence to the CTCSS tone. The signal which comes out of the IC104B is limited to a certain amplitude at the IC104A for the voice signal not to exceed the allowable band width assigned for transmission.

CIRCUITS TO SUPPRESS SPURIOUS RADIATION AND LIMIT MODULATION FCC ID: BBOFRS120C